: 0.12 g (typ.)

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LVX74FN

Dual D-Type Flip-Flop with Preset and Clear

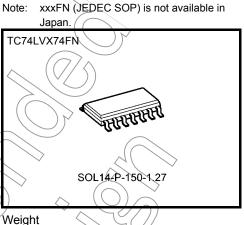
The TC74LVX74FN is a high-speed CMOS D-flip flop fabricated with silicon gate CMOS technology. Designed for use in 3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This device is suitable for low-voltage and battery operated systems.

The signal level applied to the D input is transferred to Q output during the positive going transition of the CK pulse.

 $\overline{\text{CLR}}$ and $\overline{\text{PR}}$ are independent of the CK and are accomplished by setting the appropriate input low.

An input protection circuit ensures that 0 to 5.5V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.



SOL14-P-150-1.27

Features

- High-speed: $f_{max} = 145 \text{ MHz}$ (typ.) (V_{CC} = 3.3 V)
- Low power dissipation: $I_{CC} = 2 \mu A (max) (Ta = 25 \circ C)$
- Input voltage level: $V_{IL} = 0.8 V (max) (V_{CC} = 3 V)$
 - $V_{IH} = 2.0 V (min) (V_{CC} = 3 V)$
- · Power-down protection provided on all inputs
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Pin and function compatible with 74HC74

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(5) 1Q

(6) 1Q

2Q

 $2\overline{Q}$

(9)

(8)

Pin Assignment (top view)



1PR

1CK

1D

1CLR

2PR

2CK

2D

2CLR

(4)

(3)

(2)

(1)

 $(10)_{1}$

(11)

(12)

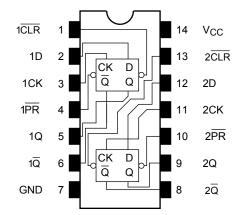
(13)

s

> C1

1D

R



Truth Table

	Inp	uts		Out	puts	Function
CLR	PR	D	СК	Q	Q	Function
L	Н	Х	Х	L	Н	Clear
Н	L	Х	Х	Н	L	Preset
L	L	Х	Х	Н	Н	±
Н	Н	L		L	Н	
Н	Н	Н		Н	L	
Н	Н	Х		Qn		No change

X: Don't care

Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	\supset V _{CC} $<$	-0.5 to 7.0	V
DC input voltage	VIŅ	-0.5 to 7.0	V
DC output voltage	VOUT	-0.5 to V _{CC} + 0.5	V
Input diode current	IIК	_20	mA
Output diode current	lok	±20	mA
DC output current	Tout	±25	mA
DC V _{CC} /ground current	-lçc	±50	mA
Power dissipation	PD	180	mW
Storage temperature	T _{stg}	–65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2.0 to 3.6	V
Input voltage	V _{IN}	0 to 5.5	V
Output voltage	V _{OUT}	0 to V _{CC}	V
Operating temperature	T _{opr}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 100	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteris	Sym- bol	Test	Condition	Vcc.(X	Min	та = 25°С Тур.	; Max	Ta = - 85 Min		Unit		
Input voltage					2.0	1.5	_	X	1.5			
	H-level	VIH	-		3.0	2.0	-(2.0			
					3.6	2.4			2.4	_	V	
	L-level	V _{IL}			2.0	— (H	0.5	—	0.5	v	
				\mathcal{A}	3.0			0.8	—	0.8		
					3.6	_ \	-	0.8	—	0.8		
	H-level	V _{OH}	((I _{OH} = −50 μA	2.0	1.9	2.0	—	1.9	_		
				Ч 0 H = −50 μA	3.0	2.9	3.0	—	2.9			
Output voltage			$(C \land$	I _{OH} = -4 mA	3,0	2.58	—	_	2.48	_	V	
Output voltage				l _{OL} = 50 μA	2.0	$\rangle -$	0	0.1	—	0.1	v	
	L-level	VOL	VIN = VIH or VIL	I _{OL} = 50 μA	3.0		0	0.1	—	0.1		
			\mathcal{I}	I _{OL} = 4 mA	∆ ^{3.0}	—	—	0.36	—	0.44		
Input leakage current			VorGND))3.6	—	—	±0.1	—	±1.0	μA		
Quiescent supply cu	irrent	Icc	VIN = Vec	or GND	3.6	—	—	2.0	—	20.0	μA	

Timing Requirements (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C	Ta =40 to 85°C	Unit	
			V _{CC} (V)	Limit	Limit		
Minimum pulse width	tw (L)		2.7	8.5	10.0	ns	
(СК)	tw (H)	-	$\textbf{3.3}\pm\textbf{0.3}$	6.0	7.0		
Minimum pulse width	t _W (L)		2.7	8.5	10.0	ns	
$(\overline{CLR}, \overline{PR})$			$\textbf{3.3}\pm\textbf{0.3}$	6.0	7.0		
Minimum set-up time	t _s		2.7	8.0	9.5	ns	
Winimum set-up time		_	$\textbf{3.3}\pm\textbf{0.3}$	5.5	6.5	115	
Minimum hold time	+.		2.7	0.5	0.5	200	
	t _h	—	$\textbf{3.3}\pm\textbf{0.3}$	0.5	0.5	ns	
Minimum removal time	+		2.7	6.5	7.5	ns	
(CLR , PR)	t _{rem}		$\textbf{3.3}\pm\textbf{0.3}$	5.0	5.0	115	

AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol Test Condition				Ta = 25°C		Ta =40 to 85°C		Unit	
			V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	
			2.7	15	_	7.3	15.0	1.0	18.5	- ns
Propagation delay time	t _{pLH}		2.1	50	_	9.8 <	18.5	1.0	22.0	
(CK-Q, Q)	tuu		3.3 ± 0.3	15	_	5.7	9.7	1.0	11.5	
	tpHL		3.3 ± 0.3	50	_	8.2	13.2	0.14	15.0	
	t _{pLH}	_	2.7	15		8,4	15.6	1.0	18.5	- ns
Propagation delay time				50	\langle	10.9	19.1	1.0	22.0	
$(\overline{CLR}, \overline{PR}-Q, \overline{Q})$	t _{pHL}		$\textbf{3.3}\pm\textbf{0.3}$	15		6.6	10.1	1.0	12.0	
				50	_((9.1	13.6	1.0	15.5	
	4		2.7 3.3 ± 0.3	15	55	135		50		MHz
Maximum clock frequency				50 <	45	>60	_	40	\rightarrow	
	f _{max}			15	95	145		80		
				50	60	85	$-\left(\right)$	50		
Output to output skew	t _{osLH} t _{osHL}	(Note 1)	2.7	50			7.5	Y)	1.5	ns
			3.3 ± 0.3	50	_	-((1.5)	1.5	115
Input capacitance	CIN			(Note 2)	—	4	10		10	pF
Power dissipation capacitance	C _{PD}		(\land)	(Note 3)	—	25		—	_	pF

Note 1: Parameter guaranteed by design. (tosLH = |tpLHm - tpLHn|, tosHL = |tpHLm - tpHLn|)

Note 2: Parameter guaranteed by design.

Note 3: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

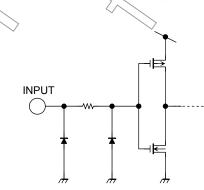
Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2 \text{ (per F/F)}$

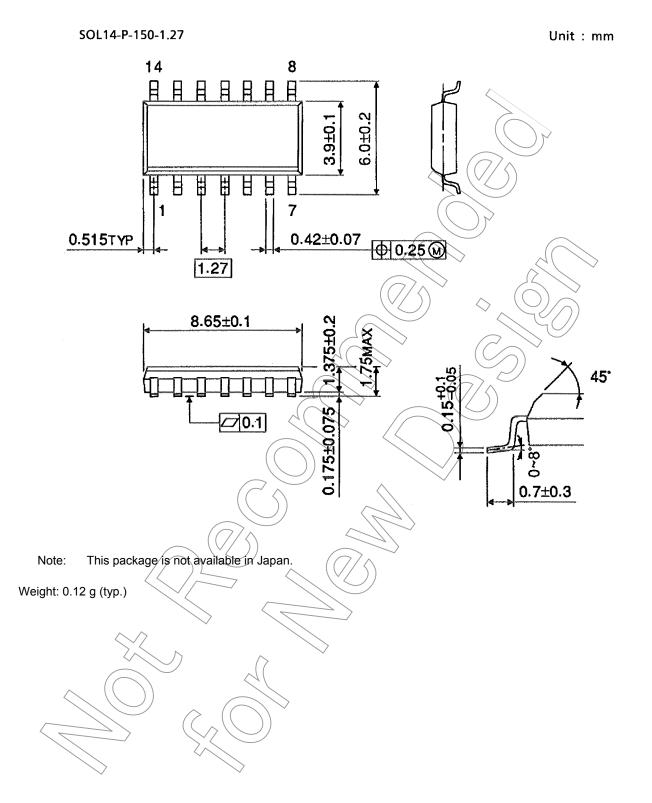
Noise Characteristics (Ta = 25°C, input: $t_r = t_f = 3^\circ n_s$, $C_L = 50 \text{ pF}$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Limit	Unit
Quiet output maximum dynamic VOL	VOLR	_	3.3	0.3	0.5	V
Quiet output minimum dynamic VOL	Volv	\rightarrow –	3.3	-0.3	-0.5	V
Minimum high level dynamic input voltage VIH	VIHD	—	3.3	_	2.0	V
Maximum low level dynamic input voltage VIL	VILD	—	3.3		0.8	V

Input Equivalent Circuit



Package Dimensions (Note)



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